

## **Application Note**

# **Code Banking**

## 78K0 Series

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#### 1. VOLTAGE APPLICATION WAVEFORM AT INPUT PIN

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between VIL (MAX) and VIH (MIN) due to noise, etc., the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between VIL (MAX) and VIH (MIN).

#### 2. HANDLING OF UNUSED INPUT PINS

Unconnected CMOS device inputs can result in malfunction. If an input pin is unconnected, it is possible that an internal input level may be generated due to noise, etc., causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND via a resistor if there is a possibility that it will be an output pin. All handling related to unused pins must be judged separately for each device and according to related specifications governing the device.

#### 3. PRECAUTION AGAINST ESD

A strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and to quickly dissipate it should it occur. Environmental control must be adequate. When it is dry, a humidifier should be used. It is recommended to avoid using insulators that easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors should be grounded. The operator should be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with mounted semiconductor devices.

#### 4. STATUS BEFORE INITIALIZATION

Power-on does not necessarily define the initial status of a MOS device. Immediately after the power source is turned ON, devices with reset functions have not yet been initialized. Hence, power-on does not guarantee output pin levels, I/O settings or contents of registers. A device is not initialized until the reset signal is received. A reset operation must be executed immediately after power-on for devices with reset functions.

#### 5. POWER ON/OFF SEQUENCE

In the case of a device that uses different power supplies for the internal operation and external interface, as a rule, switch on the external power supply after switching on the internal power supply. When switching the power supply off, as a rule, switch off the external power supply and then the internal power supply. Use of the reverse power on/off sequences may result in the application of an overvoltage to the internal elements of the device, causing malfunction and degradation of internal elements due to the passage of an abnormal current. The correct power on/off sequence must be

judged separately for each device and according to related specifications governing the device.

#### 6. INPUT OF SIGNAL DURING POWER OFF STATE

Do not input signals or an I/O pull-up power supply while the device is not powered. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Input of signals during the power off state must be judged separately for each device and according to related specifications governing the device.

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## **Chapter 1 Overview**

## 1.1 Introduction

If an application needs more than 60kB ROM the 78K0 Series reaches the limit of direct addressable memory. To overcome this limit the complete software development environment (Compiler, Linker, In-Circuit Emulator) supports a code expansion technique called banked memory.

## **Chapter 2 Memory Bank Select Function**

For NEC 78K0 Series up to 6 banks can be addressed with a bank size of 16kB. This results to a ROM size of up to 96kB banked memory plus 32kB common memory.

The main task of the compiler and linker is to place different parts of code into the same physical address range. Each time a banked function has to be called, the correct bank has to be selected. This is realized by a special function call procedure.

## 2.1 Memory Bank

The memory area from 0000H to 7FFFH should be used as basic common code area, where the bank switching is located in. The banked code area is located in the address range 8000H to BFFFH.

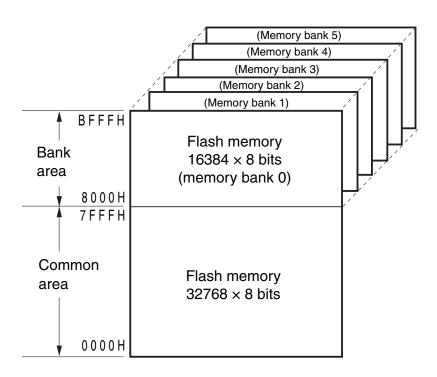


Figure 2-1 Internal Flash Memory Configuration

On 78K0 products which support the code banking, addresses can be viewed in the following two different ways:

- Memory bank number + CPU address
- Flash memory real address (HEX format [BANK])

#### (a) Memory bank number + CPU address (b) Flash memory real address (HEX FORMAT[BANK]) 1FFFFH Memory bank 5 (16K) Memory bank 5 Memory bank 4 1 C0 0 0H 1 BF F FH Memory bank 4 (16K) Memory bank 3 Memory bank 2 18000H 17FFFH Memory bank 3 (16K) Memory bank 1 14000H 13FFFH Memory bank 0 Bank Memory bank 2 (16KB) (16K) 10000H 0FFFFH Memory bank 1 (16K) 0 CO 0 OH 0 BF F F H Memory bank 0 (16K) Common (32KB) 08000H 07FFFH Area Common 00000H

The "Memory bank number + CPU address" is represented with a gap in the address space, while the flash memory real address is shown without gap in the address space.

The "Memory bank number + CPU address" is used for addressing in the user program.

Note that the HEX file output uses by default the flash memory real address.

For address representation of the other tools such as the simulator and the debugger, pls. refer to the table below:

Table 2-1 Memory Bank Address Representation

| Memory Bank<br>Number | CPU Address   | Flash Memory<br>Real Address | Address<br>Representation in<br>Debugger |
|-----------------------|---------------|------------------------------|--|
| Memory bank 0         | 08000H-0BFFFH | 08000H-0BFFFH                | 08000H-0BFFFH                            |
| Memory bank 1         |               | 0C000H-0FFFFH                | 18000H-1BFFFH                            |
| Memory bank 2         |               | 10000H-13FFFH                | 28000H-2BFFFH                            |
| Memory bank 3         |               | 14000H-17FFFH                | 38000H-3BFFFH                            |
| Memory bank 4         |               | 18000H-1BFFFH                | 48000H-4BFFFH                            |
| Memory bank 5         |               | 1C000H-1FFFFH                | 58000H-5BFFFH                            |

## 2.2 Memory Bank Select Register (BANK)

The memory bank select register (BANK) is used to select a memory bank to be used.

**Access** BANK can be set by an 8-bit memory manipulation instruction.

Address FFF3<sub>H</sub>

Initial Value Reset signal generation clears BANK to 00<sub>H</sub>.

| 7 | 6 | 5 | 4 | 3 | 2     | 1     | 0     |
|---|---|---|---|---|-------|-------|-------|
| 0 | 0 | 0 | 0 | 0 | BANK2 | BANK1 | BANK0 |
| R | R | R | R | R | R/W   | R/W   | R/W   |

| BANK2 | BANK1      | BANK0 | Description                             |
|-------|------------|-------|---|
| 0     | 0          | 0     | Common area (32K) + memory bank 0 (16K) |
| 0     | 0          | 1     | Common area (32K) + memory bank 1 (16K) |
| 0     | 1          | 0     | Common area (32K) + memory bank 2 (16K) |
| 0     | 1          | 1     | Common area (32K) + memory bank 3 (16K) |
| 1     | 0 0        |       | Common area (32K) + memory bank 4 (16K) |
| 1     | 0          | 1     | Common area (32K) + memory bank 5 (16K) |
| Oth   | er than ab | ove   | Setting prohibited                      |

#### Caution

Be sure to change the value of the BANK register in the common area (0000H to 7FFFH). If the value of the BANK register is changed in the bank area (8000H to BFFFH), an inadvertent program loop occurs in the CPU. Therefore, never change the value of the BANK register in the bank area.

## 2.3 Selecting Memory Bank

The memory bank selected by the memory bank select register (BANK) is reflected on the bank area and can be addressed. Therefore, to access a memory bank different from the one currently selected, that memory bank must be selected by using the BANK register.

The value of the BANK register must not be changed in the bank area (8000H to BFFFH). Therefore, to change the memory bank, branch an instruction to the common area (0000H to 7FFFH) and change the value of the BANK register in that area.

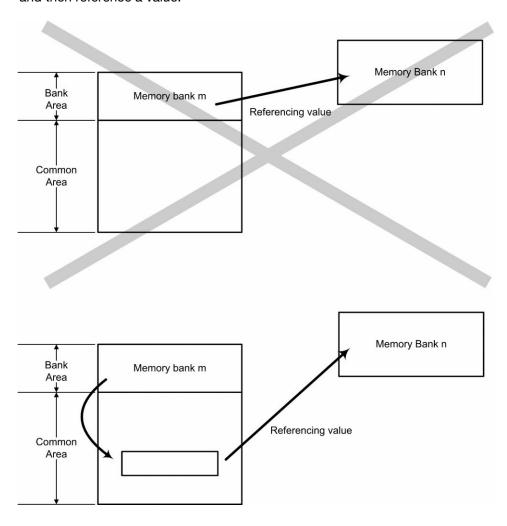
#### Caution

- 1. Instructions cannot be fetched between different memory banks
- Branching and accessing cannot be directly executed between different memory banks. Execute branching or accessing between different memory banks via the common area.
- 3. Allocate interrupt servicing in the common area.
- 4. An instruction that extends from 7FFFH to 8000H can only be executed in memory bank 0.

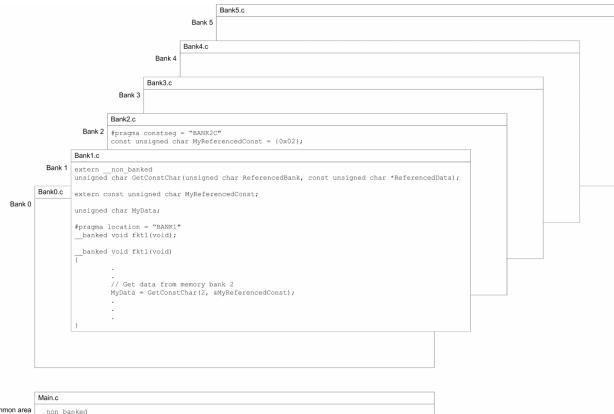
## 2.3.1 Referencing values between memory banks

Values cannot be directly referenced from one memory bank to another.

To access another memory bank from one memory bank, branch once to the common area (0000H to 7FFFH), change the setting of the BANK register there, and then reference a value.



## Software example (to read a constant located on memory bank 2 referenced from memory bank 1):

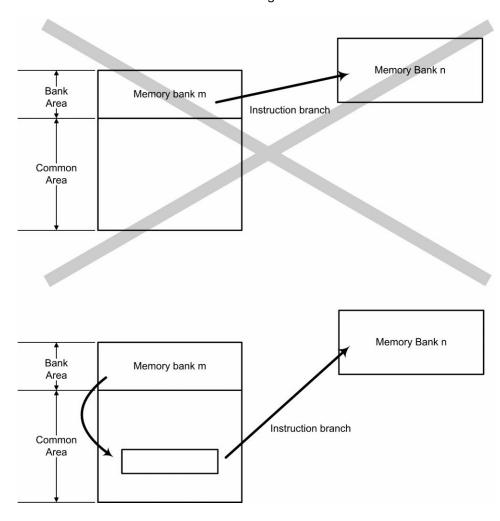


## 

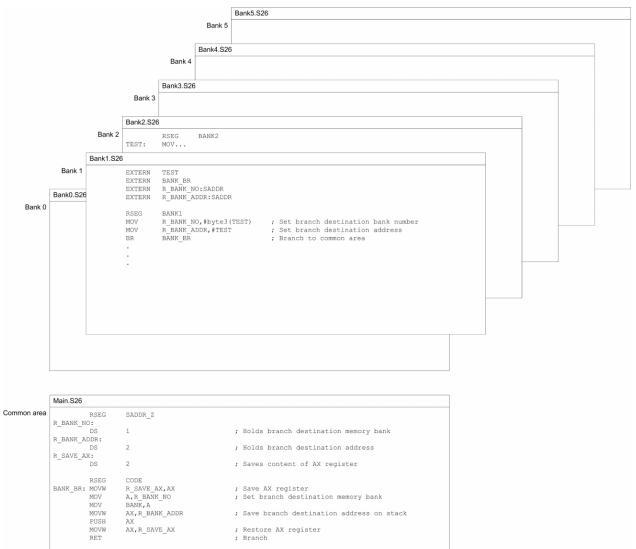
### 2.3.2 Instruction Branch Between Memory Banks

Instructions cannot branch directly from one memory bank to another.

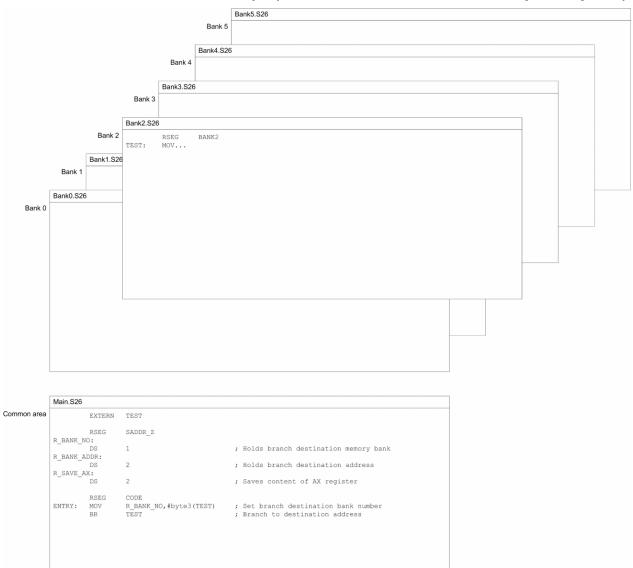
To branch an instruction from one memory bank to another, branch once to the common area (0000H to 7FFFH), change the setting of the BANK register there, and then execute the branch instruction again.



### Software example (to branch between memory banks)



### Software example (to branch from the common area to any memory bank)

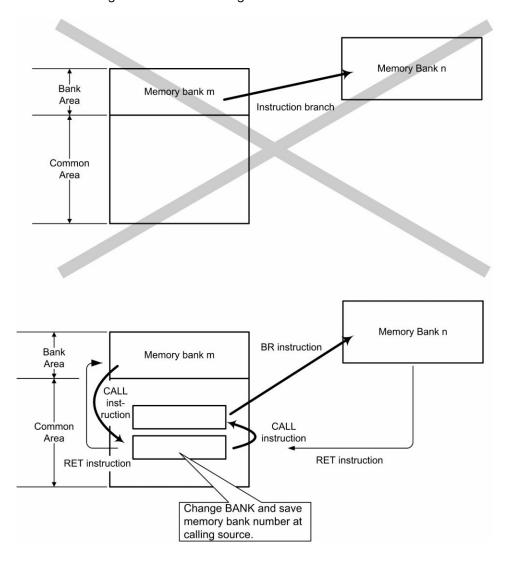


### 2.3.3 Subroutine call between memory banks

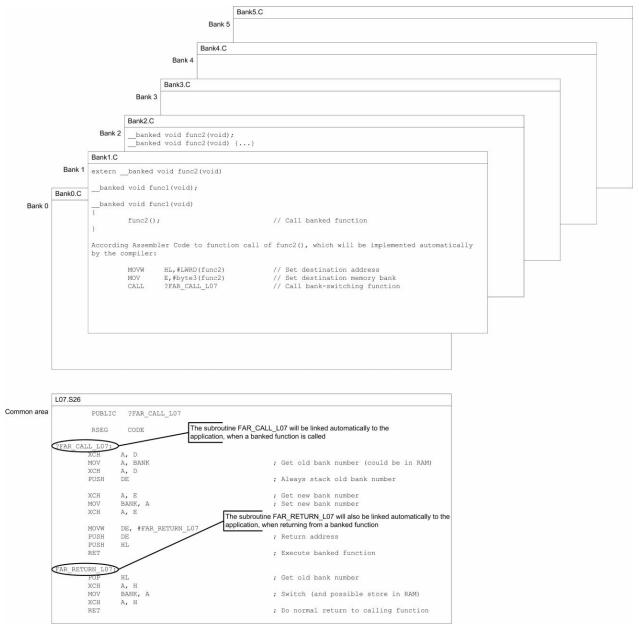
Subroutines cannot be directly called between memory banks.

To call a subroutine between memory banks, branch once to the common area (0000H to 7FFFH), specify the memory bank at the calling destination by using the BANK register there, execute the CALL instruction, and branch to the call destination by that instruction.

At this time, save the current value of the BANK register to RAM. Restore the value of the BANK register before executing the RET instruction.



## Software example (to call a function on a memory bank from another memory bank)

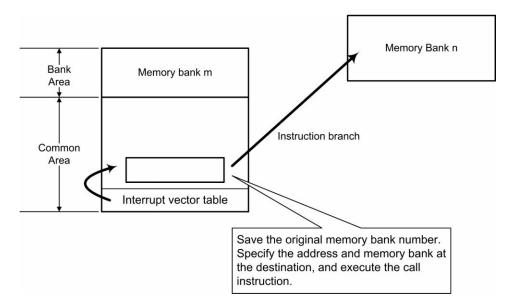


### 2.3.4 Instruction branch to bank area by interrupt

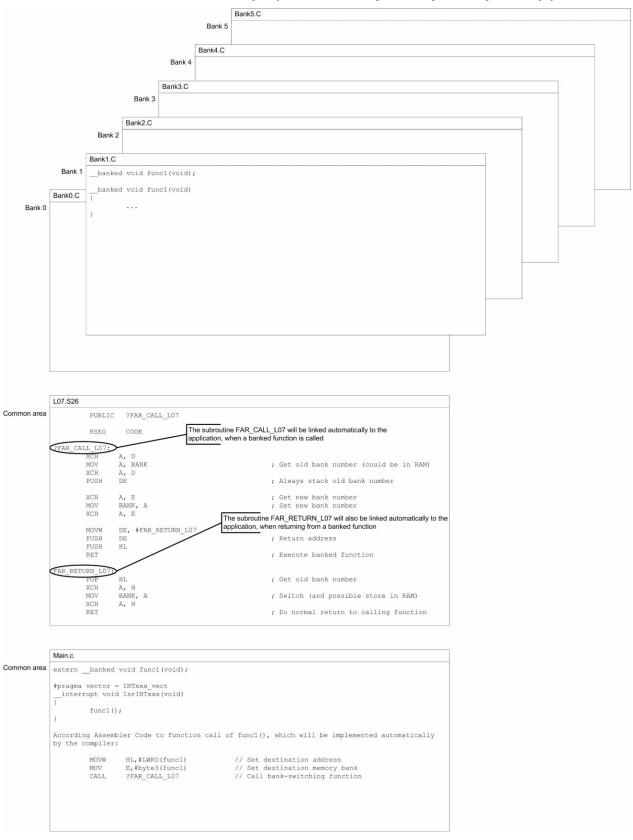
When an interrupt occurs, instructions can branch to the memory bank specified by the BANK register by using the vector table, but it is difficult to identify the BANK register when the interrupt occurs.

Therefore, specify the branch destination address specified by the vector table in the common area (0000H to 7FFFH), specify the memory bank at the branch destination by using the BANK register in the common area, and execute the CALL instruction.

At this time, save the BANK register value before the change to RAM, and restore the value of the BANK register before executing the RETI instruction.



#### Software example (to branch to any memory bank by interrupt)



## **Chapter 3 Linker Command File (\*.XCL)**

The IAR XLINK linker operation can be controlled by so-called XLINK options, which can be specified in the linker command (\*.XCL) file.

In applications which are using the code expansion technique code banking, the linker has to be informed about the number and the size of the code memory banks.

This can be done in the linker command (\*.XCL) file by setting the following options.

```
// Used with banked functions only // Start and end address of the code bank area.
//
       Number of banks in the code bank area.
       Remove comments and modify numbers if used from command line.
//
//-----
-D_CODEBANK_START=8000
-D CODEBANK END=BFFF
-D CODEBANK BANKS=6
     Banked functions code segment.
//
//
      The following code segments are available:
      - BCODE segment uses all banks
- BANKx,BANKCx segments use only bank x
//
//
//
//CODE
             Default segment for program code.
Holds all banked program code
List of defined banked code and banked const segments
, DCODE
//BANKn
//R^**
//_CODEBANK_START Start address of the banked area in hex
// CODE BANKS Decimal number of available banked segments
-P(CODE)BCODE=[ CODEBANK START- CODEBANK END] * CODEBANK BANKS+10000
-Z(CODE)BANKO,BANKC0=[(_CODEBANK_START+00000)-(_CODEBANK_END+00000)]
-Z(CODE)BANK1,BANKC1=[(_CODEBANK_START+10000)-(_CODEBANK_END+10000)]
-Z(CODE)BANK2,BANKC2=[(_CODEBANK_START+20000)-(_CODEBANK_END+20000)]
-Z(CODE)BANK3,BANKC3=[(_CODEBANK_START+30000)-(_CODEBANK_END+30000)]
-Z(CODE)BANK4,BANKC4=[(CODEBANK START+40000)-(CODEBANK END+40000)]
-Z(CODE)BANK5,BANKC5=[(_CODEBANK_START+50000)-(_CODEBANK_END+50000)]
```

The above used XLINK options forces the IAR XLINK linker to use logical addresses for the code memory banks as described in column *Address Representation in Debugger of Table 2-1 on page 10*.

This means, that these XLINK options can only be used, if the Debugger in the target Debug of the IAR Embedded Workbench is used in order to create a C-SPY Debugger or NEC-Debugger output file.

In case that a HEX-file in the target Release of the IAR Embedded Workbench shall be generated in order to program a device with a flash programmer, the address representation must be changed to physical addresses as described in column *Flash Memory Real Address of Table 2-1 on page 10*.

Logical to physical address translation can be set in the linker command (\*.XCL) file by adding the following options.

```
-M28000-2BFFF=10000-13FFF
-M38000-3BFFF=14000-17FFF
-M48000-4BFFF=18000-1BFFF
-M58000-5BFFF=1C000-1FFFF
```

#### Note

- NEC provides for all devices two linker command (\*.XCL) files, one for use with the debugger and one for generation of the HEX-file. The linker command (\*.XCL) file for HEX-file generation has the additional suffix HEX in the file name, e.g. DF054780\_HEX\_V4.XCL
- 2. Please use the following linker output file formats:
  - xcoff78k if the NEC Debugger is used, and
  - *intel-extended as segmented variant* if the real device shall be programmed with a flash programmer.
  - The linker output file format for the IAR C-SPY Debugger is selected automatically, if the IAR Embedded Workbench editor is used.

## **Revision History**

| Chapter | Page | Description   |  |
|---------|------|---|--|
| 3       | 21   | Logical to physical address translation table has been revised. |  |

